

Vishay High Power Products

Medium Power Thyristors (Stud Version), 50 A



TO-20	ns A C	(TO	-65)

PRODUCT SUMMARY		
I _{T(AV)}	50 A	

FEATURES

- · High current rating
- Excellent dynamic characteristics
- $dV/dt = 1000 V/\mu s$ option
- Superior surge capabilities
- · Standard package
- Metric threads version available
- Types up to 1200 V V_{DRM}/V_{RRM}
- · RoHS compliant

TYPICAL APPLICATIONS

- · Phase control applications in converters
- · Lighting circuits
- · Battery charges
- · Regulated power supplies and temperature and speed control circuit
- · Can be supplied to meet stringent military, aerospace and other high reliability requirements

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	VALUES	UNITS				
1		50	А				
I _{T(AV)}	T _C	94	°C				
I _{T(RMS)}		80	Α				
I _{TSM}	50 Hz	1430	A				
	60 Hz	1490	A				
l ² t	50 Hz	10.18	kA ² s				
1-1	60 Hz	9.30	KA-S				
V _{DRM} /V _{RRM}		100 to 1200	V				
t _q	Typical	110	μs				
T_J		- 40 to 125	°C				

50RIA Series

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ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS									
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE ⁽¹⁾ V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE ⁽²⁾ V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA					
	10	100	150						
	20	200	300						
	40	400	500						
50RIA	60	600	700	15					
	80	800	900						
	100	1000	1100						
	120	1200	1300						

Notes

⁽²⁾ For voltage pulses with $t_p \le 5$ ms

ABSOLUTE MAXIMUM R	ATINGS					
PARAMETER	SYMBOL		TEST CON	IDITIONS	VALUES	UNITS
Maximum average on-state current	I _{T(AV)}	180° einueo	idal conduction		50	Α
at case temperature	TI(AV)	100 311030	ndar conduction		94	°C
Maximum RMS on-state current	I _{T(RMS)}				80	Α
		t = 10 ms	No voltage		1430	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		1490	۸
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		1200	Α
		t = 8.3 ms	reapplied	Sinusoidal half wave,	1255	
Maximum I ² t for fusing		t = 10 ms	No voltage initial $T_J = T_J$ mare reapplied	initial $T_J = T_J$ maximum	10.18	kA ² s
	t = 8.3 m	t = 8.3 ms			9.30	
	,	t = 10 ms	100 % V _{RRM}		7.20	
		t = 8.3 ms	reapplied		6.56	
Maximum $I^2\sqrt{t}$ for fusing	I²√t	$t = 0.1$ to 10 ms, no voltage reapplied, $T_J = T_J$ maximum		101.8	kA²√s	
Low level value of threshold voltage	V _{T(TO)1}	$(16.7 \% \text{ x } \pi \text{ x } I_{T(AV)} < I < \pi \text{ x } I_{T(AV)}), T_J = T_J \text{ maximum}$		0.94	V	
High level value of threshold voltage	V _{T(TO)2}	(π x I _{T(AV)} <	I < 20 x π x I _{T(A\}	(J)), $T_J = T_J$ maximum	1.08	V
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum		4.08	mΩ	
High level value of on-state slope resistance	r _{t2}	$(\pi \times I_{T(AV)} < I < 20 \times \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			3.34	1117.5
Maximum on-state voltage	V_{TM}	I _{pk} = 157 A,	T _J = 25 °C		1.60	V
Maximum holding current	I _H	T_J = 25 °C, anode supply 22 V, resistive load, initial I_T = 2 A		200	mA	
Latching current	ΙL	Anode supp	oly 6 V, resistive	load	400	1

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 $^{^{(1)}}$ Units may be broken over non-repetitively in the off-state direction without damage, if dl/dt does not exceed 20 A/ μ s



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SWITCHING					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum rate of	V _{DRM} ≤ 600 V	dl/dt	T_C = 125 °C, V_{DM} = Rated V_{DRM} , Gate pulse = 20 V, 15 Ω, t_p = 6 μs, t_r = 0.1 μs maximum	200	A/us
rise of turned-on current	$V_{DRM} \le 1600 \text{ V}$		$I_{TM} = (2 \text{ x rated dI/dt}) \text{ A}$	100	Ανμδ
Typical delay time		t _d	T_C = 25 °C, V_{DM} = Rated V_{DRM} , I_{TM} = 10 A dc resistive circuit Gate pulse = 10 V, 15 Ω source, t_p = 20 μ s	0.9	
Typical turn-off time		tq	T_C = 125 °C, I_{TM} = 50 A, reapplied dV/dt = 20 V/ μ s dIr/dt = -10 A/ μ s, V_R = 50 V	110	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of	dV/dt	$T_J = T_J$ maximum linear to 100 % rated V_{DRM}	200	V/µs
off-state voltage	uv/ut	$T_J = T_J$ maximum linear to 67 % rated V_{DRM}	500 ⁽¹⁾	ν/μS

Note

 $^{^{(1)}}$ Available with dV/dt = 1000 V/ μ s, to complete code add S90 i.e. 50RIA120S90

TRIGGERING					
PARAMETER	SYMBOL	TES	T CONDITIONS	VALUES	UNITS
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum, $t_p \le 5$	5 ms	10	14/
Maximum average gate power	P _{G(AV)}			2.5	W
Maximum peak positive gate current	I _{GM}			2.5	Α
Maximum peak positive gate voltage	+V _{GM}			20	V
Maximum peak negative gate voltage	-V _{GM}			10	V
		T _J = - 40 °C	Maximum required gate trigger current/voltage are the lowest value which will trigger all units 6 V	250	mA
DC gate current required to trigger	I _{GT}	T _J = 25 °C		100	
		T _J = 125 °C		50	
	.,	T _J = - 40 °C	anode to cathode applied	3.5	
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C		2.5	V
DC gate current not to trigger	I _{GD}	$T_J = T_J$ maximum, $V_{DRM} = Rated voltage$	Maximum gate current/voltage not to trigger is the maximum value	5.0	mA
DC gate voltage not to trigger	V_{GD}	$T_J = T_J$ maximum	which will not trigger any unit with rated V _{DRM} anode to cathode applied	0.2	V

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THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction and storage temperature range	T _J , T _{Stg}		- 40 to 125	°C		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.35	K/W		
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased		IV/W		
Allowable mounting torque		Non-lubricated threads	3.4 + ^{0 - 10} % (30)	N · m		
Allowable mounting torque		Lubricated threads	2.3 + ^{0 - 10} % (20)	(lbf · in)		
Approximate weight			28	g		
Approximate weight			1.0	OZ.		
Case style		See dimensions - link at the end of datasheet	TO-208A0	C (TO-65)		

△R _{thJC} CONDUCTION	ON			
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS
180°	0.078	0.057		
120°	0.094	0.098		
90°	0.120	0.130	$T_J = T_J \text{ maximum}$	K/W
60°	0.176	0.183		
30°	0.294	0.296		

Note

• The table above shows the increment of thermal resistance RthJC when devices operate at different conduction angles than DC

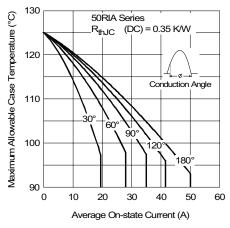


Fig. 1 - Current Ratings Characteristics

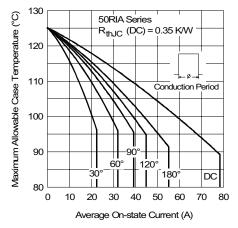


Fig. 2 - Current Ratings Characteristics

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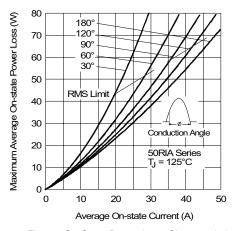


Fig. 3 - On-State Power Loss Characteristics

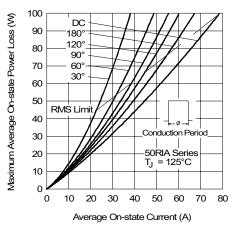


Fig. 4 - On-State Power Loss Characteristics

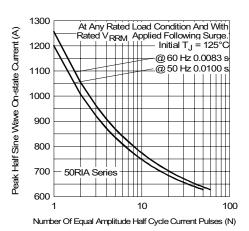


Fig. 5 - Maximum Non-Repetitive Surge Current

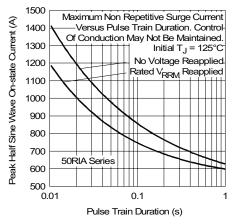


Fig. 6 - Maximum Non-Repetitive Surge Current

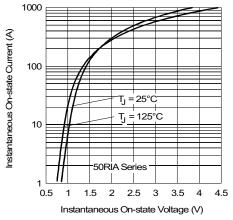


Fig. 7 - Forward Voltage Drop Characteristics

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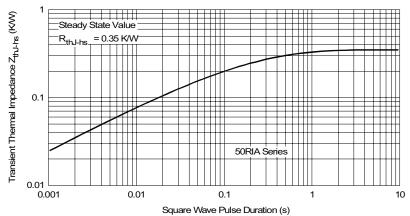
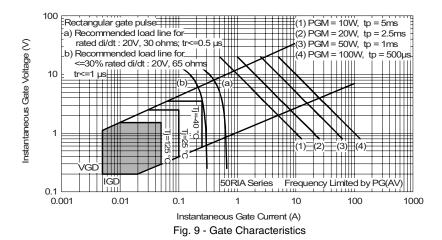
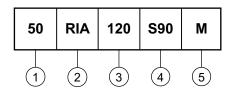


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics



ORDERING INFORMATION TABLE

Device code



1 - Current code

2 - Essential part number

Voltage code x 10 = V_{RRM} (see Voltage Ratings table)

4 - Critical dV/dt:

• None = 500 V/µs (standard value)

• S90 = 1000 V/µs (special selection)

• None = Stud base TO-208AC (TO-65) 1/4" 28UNF-2A

• M = Stud base TO-208AC (TO-65) M6 x 1

LINKS TO RELAT	TED DOCUMENTS
Dimensions	http://www.vishay.com/doc?95334





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